

Aluminum Nitride Terminations

30 Watts, 50 Ω



Features

- DC – 3.0 GHz
- 30 Watts
- Aluminum Nitride (AlN) Ceramic
- Terminal for Lead Attachment
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

General Specifications

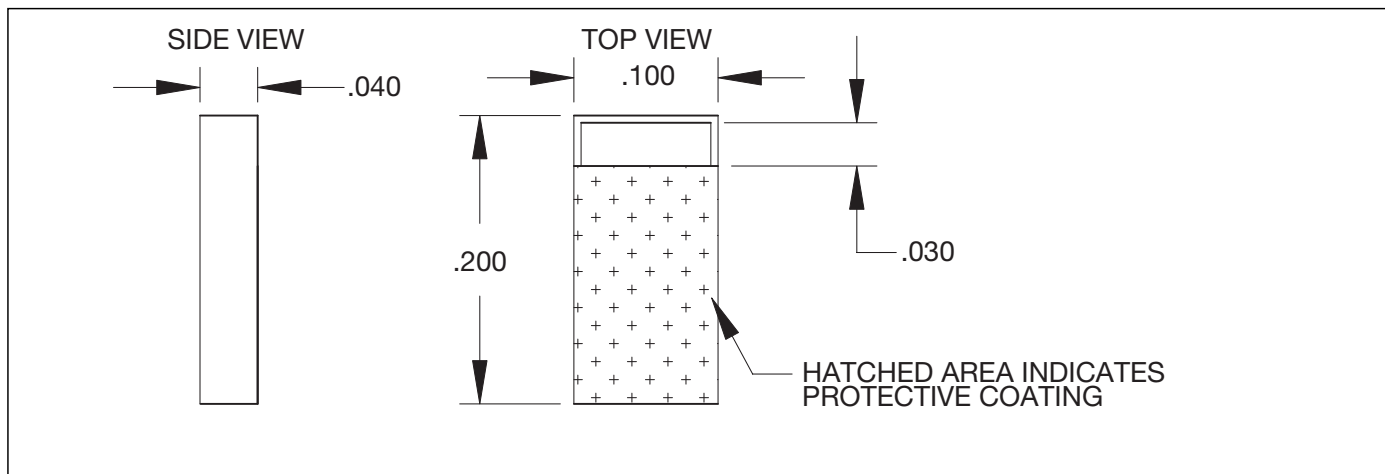
Resistive Element:	Thick film
Substrate:	Aluminum nitride ceramic
Terminals:	Tin/Lead, 90/10 over nickel

Electrical Specifications

Resistance Value:	50 ohms, $\pm 2\%$
Frequency Range:	DC - 3.0 GHz
Power:	30 Watts
V.S.W.R.:	1.25:1

Notes: Tolerance is ± 0.10 , unless otherwise specified. Operating temperature is -55°C to $+150^{\circ}\text{C}$ (see chart). Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions are in inches.
Specifications subject to change without notice.

Outline Drawing



VER. 12/5/01



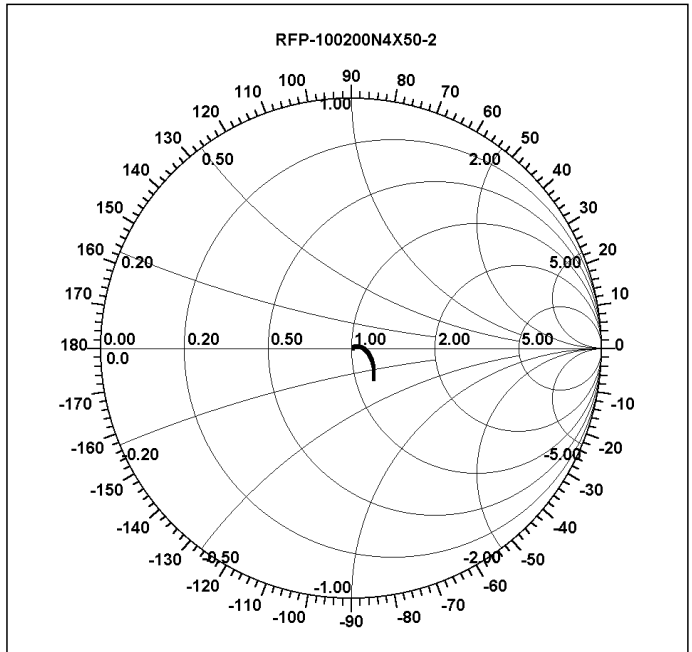
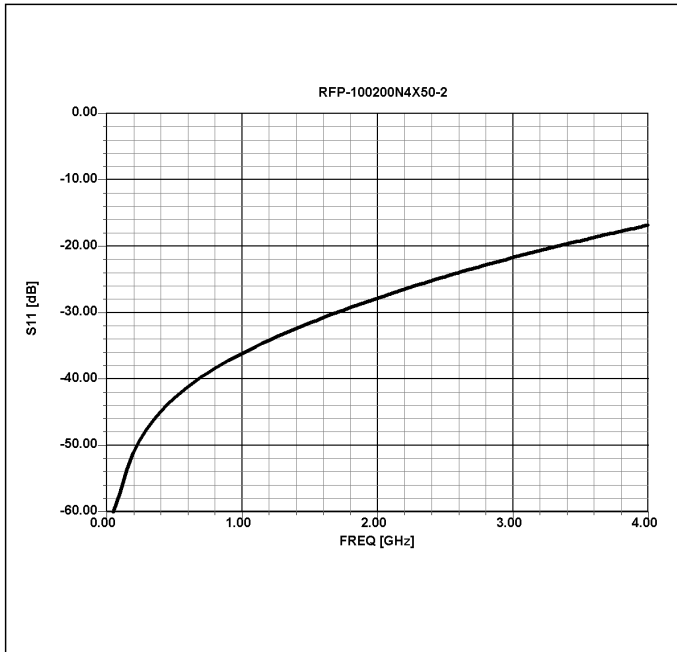
Available on Tape and Reel for Pick and Place Manufacturing.

Sales Desk USA: Voice: (800) 544-2414 Fax: (315) 432-9121
Sales Desk Europe: Voice: (+44) 23 92 232392 Fax: (+44) 23 92 251369

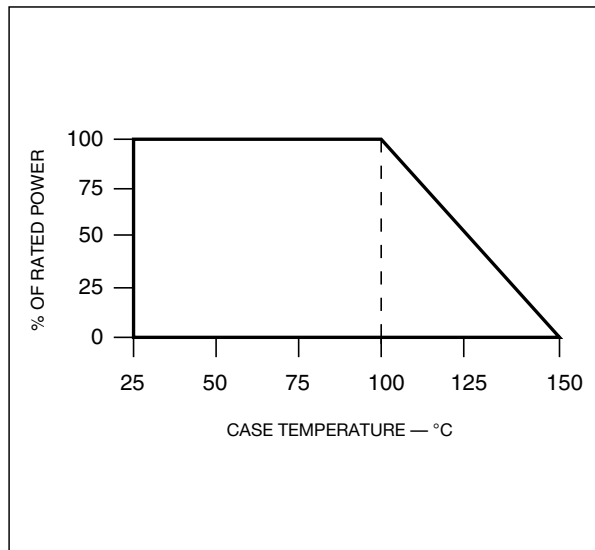
Model RFP-100200N4X50-2

Anaren**RF Power**

Typical Performance

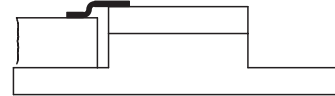


Power Derating



Suggested Mounting Procedures

.025 MIN.
(2 PLACES)



BOARD LOWER
THAN LEAD.

SUGGESTED STRESS RELIEF METHODS

SCALE: NONE

1. Make sure that the devices are mounted on flat surfaces (.001" under the device) to optimize the heat transfer.
2. Position device on mounting surface and solder in place using an SN96 type solder.
3. Solder leads in place using an SN63 type solder with a controlled temperature iron (700°F).

Available on Tape and Reel for Pick and Place Manufacturing.

